





	<h2 style="color: red;">FQP13N10</h2>
	<p>Hersteller-Teilenummer: FQP13N10</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 12.8A TO-220</p> <p>Datenblätter: 1.FQP13N10.pdf 2.FQP13N10.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 78502 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP13N10
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 12.8A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	78502 pcs Stock
Hersteller Standard Vorlaufzeit	7 Weeks
detaillierte Beschreibung	N-Channel 100V 12.8A (Tc) 65W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12.8A (Tc)
Rds On (Max) @ Id, Vgs	180 mOhm @ 6.4A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	450pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP13N10 ist neu im Original, Suche FQP13N10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N10 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP13N10: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP13N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N10C FSC FQP13N10C FSC</p>	 <p>FQP13N50 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 12.5A TO-220</p>	 <p>FQP13N06L FQP13N06 Original FQP13N06L FQP13N06 Original</p>
 <p>FQP13N06 Fairchild/ON Semiconductor MOSFET N-CH 60V 13A TO-220</p>	 <p>FQP13N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>	 <p>FQP13N10 Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p>FQP13N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>

heiße Teile

Mehr

⊗ FQP10N65C	↔ FQP10N80	⇒ FQP11N40C	D FQP11N40C	↔ FQP11N50CF
⊣ FQP11N50CF	⊗ FQP11N60	D FQP11N60C	⇒ FQP11N65C	↔ FQP11P06
⊗ FQP11P06	⊣ FQP12N20	⊗ FQP12N60	↔ FQP12N60	↔ FQP12N60C
D FQP12N60C	⊗ FQP12N65C	⊣ FQP12P10	⊗ FQP12P10	↔ FQP12P20
⇒ FQP12P20	↔ FQP13N06	⊗ FQP13N06	⊣ FQP13N06L	↔ FQP13N06L
↔ FQP13N10	⇒ FQP13N10L	D FQP13N10L	⊗ FQP13N50	⊣ FQP13N50
⊗ FQP13N50C	D FQP13N50C	⇒ FQP13N60C	↔ FQP140N03	↔ FQP140N03L
⊣ FQP14N15	⊗ FQP14N15	↔ FQP14N30	⇒ FQP14N30	↔ FQP14N80
⊗ FQP14N80C	⊣ FQP15N16	⊗ FQP15N30	D FQP15N50	↔ FQP15N60
↔ FQP15N65	⊗ FQP15N80	⊣ FQP15P12	⊗ FQP15P12	↔ FQP16N15

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